FORM PTO-1449 (Equivalent)

U.S. Department of Commerce Patent and Trademark Office

U.S. Application Serial No. 10/829,016

Atty. Docket No. AM-9230

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(Use several sheets if necessary)

Soo Young Choi et al.

Applicants

April 30, 2004 Filing Date

Unknown

		Group						
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Examiner Initial	Document Number	Issue Date	Name Law et al. Law et al.		Class	Subclass	Filing Date If Appropriate	
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<u></u>	2002/01468	79 10,	/10/02	Fu et al.	438	230		12/21/01
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Examiner	Document Number			Name	Class Subclass		Translation (If Appropriate)	
RINS.	EP 1168427	01/02/02	Tan et a	1.	H01L	21/318		

Examiner

Date Considered

December 21, 200

Examined: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Received, 6-23-04

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Stephen V. Smoot

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OIP FORM PTO-1449

COIP (Equivalent)

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(Use several sheets if necessary)

Soo Young Choi et al.
Applicants

April 20, 2004 Filing Date

2813 Group

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